

### Features

$V_{DS} = 20V$

- $R_{DS(ON)} = 300m\Omega$  (typ.) @  $V_{GS} = 2.5V$
- $R_{DS(ON)} = 250m\Omega$  (typ.) @  $V_{GS} = 4.5V$
- ESD Protected up to 2KV

### Application

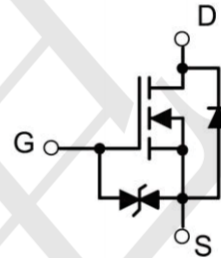
- Load/Power Switching
- Interfacing Switching
- Battery Management for Ultra Small Portable Electronics
- Logic Level Shift

### Package and Pin Configuration

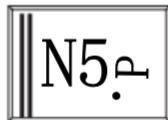


DFN1006-3L

### Circuit diagram



Marking:



### Absolute Maximum Ratings ( $T_A = 25^\circ C$ unless otherwise noted)

| Parameter                                            | Symbol          | Value     | Unit         |
|------------------------------------------------------|-----------------|-----------|--------------|
| Drain-Source Voltage                                 | $V_{DS}$        | 20        | V            |
| Gate-Source Voltage                                  | $V_{GS}$        | $\pm 8$   | V            |
| Continuous Drain Current                             | $I_D$           | 0.9       | A            |
| Pulsed Drain Current ( $t=300\mu s$ ) <sup>(1)</sup> | $I_{DM}$        | 1.5       | A            |
| Power Dissipation <sup>(2)</sup>                     | $P_D$           | 0.35      | W            |
| Thermal Resistance from Junction to Ambient          | $R_{\theta JA}$ | 357       | $^\circ C/W$ |
| Junction Temperature                                 | $T_J$           | 150       | $^\circ C$   |
| Storage Temperature                                  | $T_{STG}$       | -55~ +150 | $^\circ C$   |

### Electrical Characteristics ( $T_A = 25^\circ\text{C}$ unless otherwise noted )

| Parameter                                 | Symbol        | Test Condition                                                 | Min | Type | Max      | Unit    |
|-------------------------------------------|---------------|----------------------------------------------------------------|-----|------|----------|---------|
| Static Characteristics                    |               |                                                                |     |      |          |         |
| Drain-source breakdown voltage            | $V_{(BR)DSS}$ | $V_{GS} = 0V, I_D = 250\mu A$                                  | 20  | 25   |          | V       |
| Zero gate voltage drain current           | $I_{DSS}$     | $V_{DS} = 20V, V_{GS} = 0V$                                    |     |      | 1        | $\mu A$ |
| Gate-body leakage current                 | $I_{GSS}$     | $V_{GS} = \pm 18V, V_{DS} = 0V$                                |     |      | $\pm 10$ | $\mu A$ |
| Gate threshold voltage <sup>(3)</sup>     | $V_{GS(th)}$  | $V_{DS} = V_{GS}, I_D = 250\mu A$                              | 0.5 | 0.7  | 1.1      | V       |
| Drain-source on-resistance <sup>(3)</sup> | $R_{DS(on)}$  | $V_{GS} = 4.5V, I_D = 500mA$                                   |     | 250  | 400      | mΩ      |
|                                           |               | $V_{GS} = 2.5V, I_D = 500mA$                                   |     | 300  | 500      |         |
| Forward tranconductance                   | $g_{FS}$      | $V_{DS} = 10V, I_D = 500mA$                                    |     |      | 1.2      | S       |
| Dynamic characteristics <sup>(4)</sup>    |               |                                                                |     |      |          |         |
| Input Capacitance                         | $C_{iss}$     | $V_{DS} = 10V, V_{GS} = 0V, f = 1MHz$                          |     | 45   |          | pF      |
| Output Capacitance                        | $C_{oss}$     |                                                                |     | 9    |          |         |
| Reverse Transfer Capacitance              | $C_{rss}$     |                                                                |     | 6    |          |         |
| Switching Characteristics <sup>(4)</sup>  |               |                                                                |     |      |          |         |
| Turn-on delay time                        | $t_{d(on)}$   | $V_{DD} = 10V, I_D = 500mA,$<br>$V_{GS} = 4.5V, R_G = 6\Omega$ |     | 20   |          | ns      |
| Turn-on rise time                         | $t_r$         |                                                                |     | 90   |          |         |
| Turn-off delay time                       | $t_{d(off)}$  |                                                                |     | 750  |          |         |
| Turn-off fall time                        | $t_f$         |                                                                |     | 400  |          |         |
| Source-Drain Diode characteristics        |               |                                                                |     |      |          |         |
| Diode Forward voltage <sup>(3)</sup>      | $V_{DS}$      | $I_S = 0.15A, V_{GS} = 0V$                                     |     |      | 1.3      | V       |

## Characteristic Curves

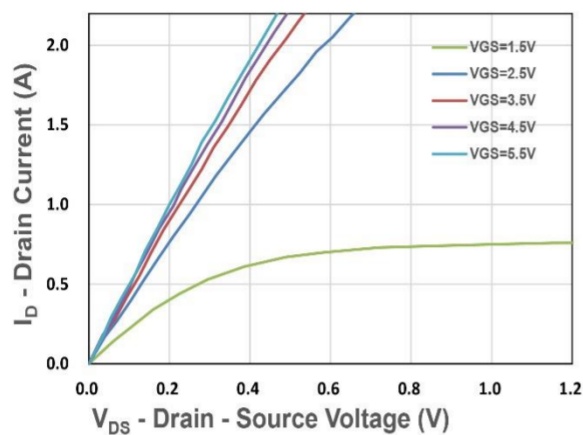


Figure 1. Output Characteristics

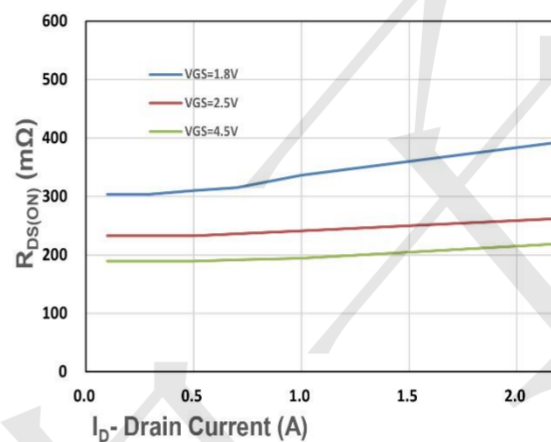


Figure 2. On-Resistance vs.  $I_D$

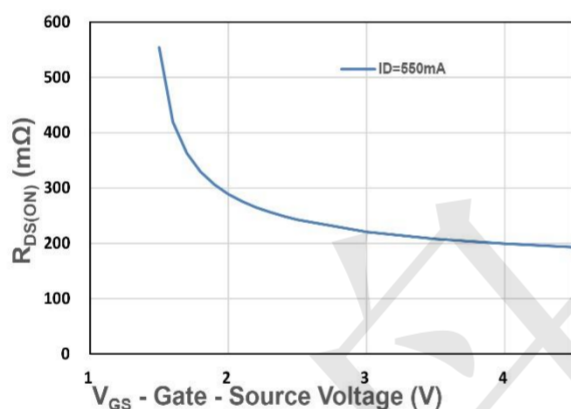


Figure 3. On-Resistance vs.  $V_{GS}$

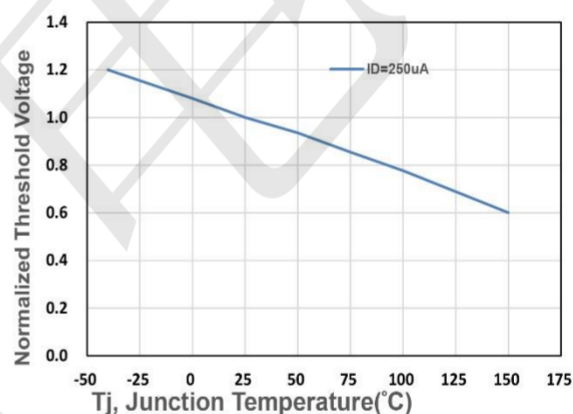


Figure 4. Gate Threshold Voltage

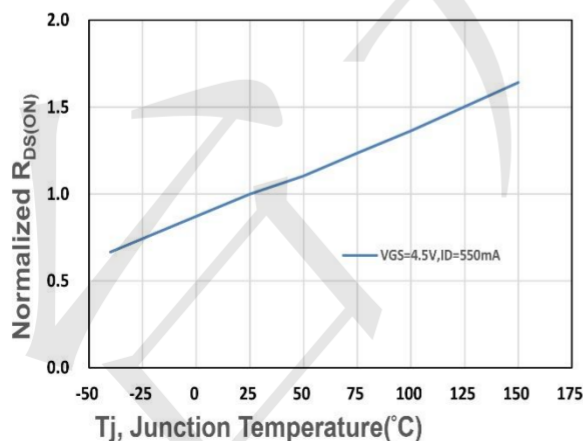


Figure 5. Drain-Source On Resistance

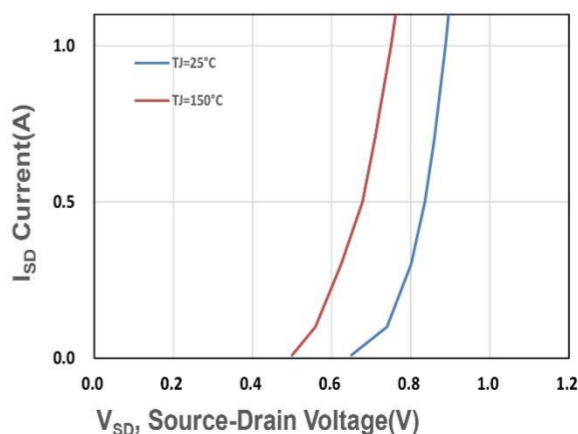


Figure 6. Source-Drain Diode Forward

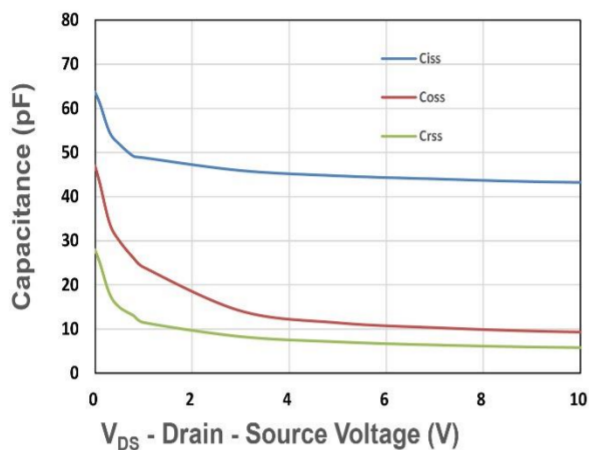


Figure 7. Capacitance

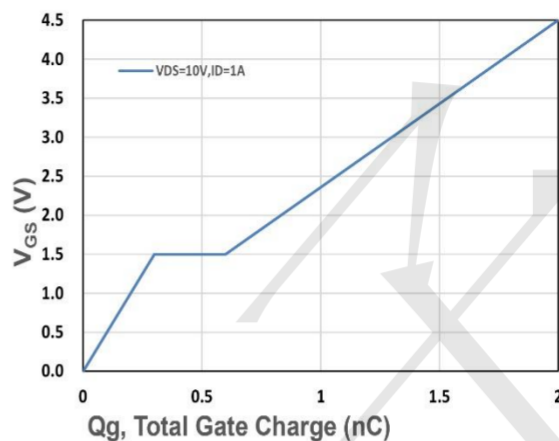


Figure 8. Gate Charge Characteristics

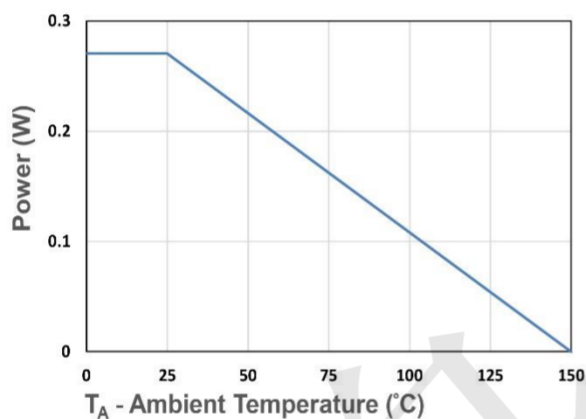


Figure 9. Power Dissipation

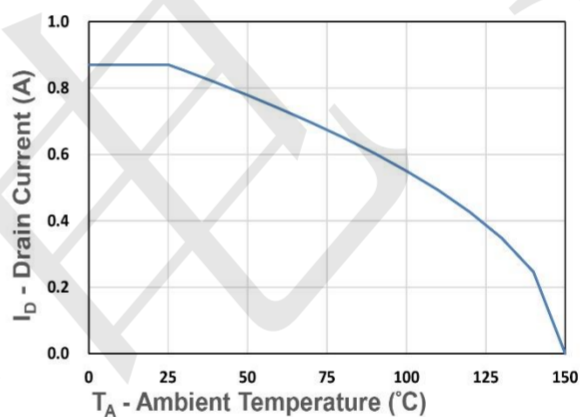


Figure 10. Drain Current

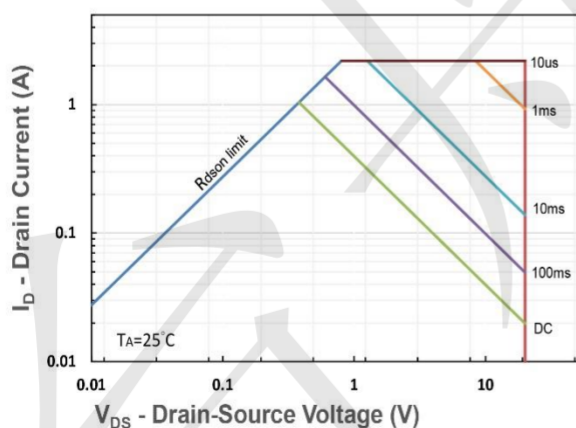


Figure 11. Safe Operating Area

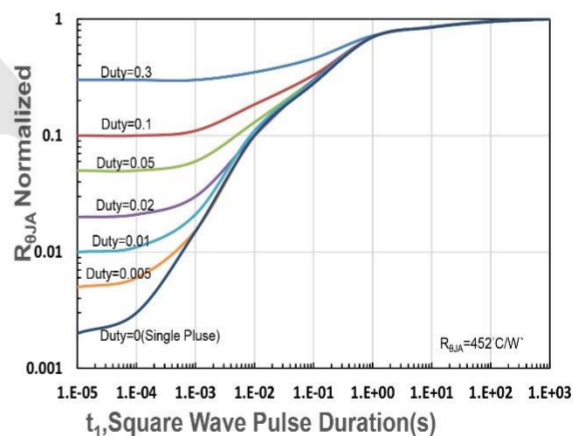
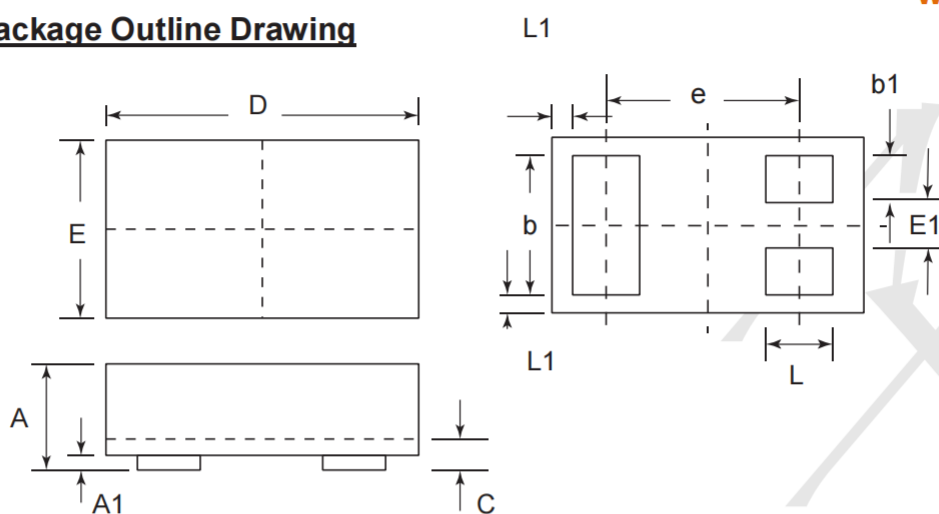


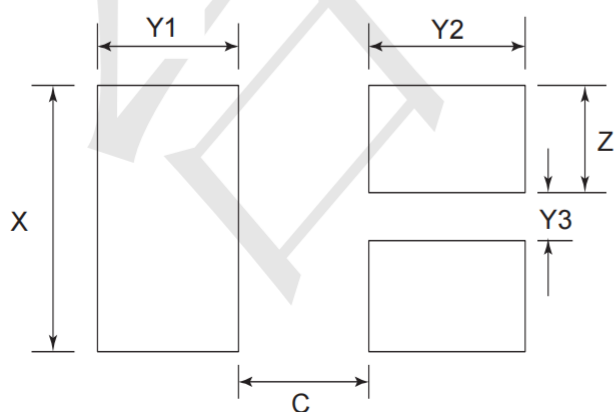
Figure 12.  $R_{\theta JA}$  Transient Thermal Impedance

**DFN1006-3L Package Outline Drawing**



| SYM | DIMENSIONS  |      |      |            |       |       |
|-----|-------------|------|------|------------|-------|-------|
|     | MILLIMETERS |      |      | INCHES     |       |       |
|     | MIN         | NOM  | MAX  | MIN        | NOM   | MAX   |
| A   | 0.45        | 0.50 | 0.55 | 0.018      | 0.020 | 0.022 |
| A1  | 0.00        | 0.02 | 0.05 | 0.000      | 0.001 | 0.002 |
| b   | 0.45        | 0.50 | 0.55 | 0.018      | 0.020 | 0.022 |
| b1  | 0.10        | 0.15 | 0.20 | 0.004      | 0.006 | 0.008 |
| C   | 0.12        | 0.15 | 0.18 | 0.005      | 0.006 | 0.007 |
| D   | 0.95        | 1.00 | 1.05 | 0.037      | 0.039 | 0.041 |
| e   | 0.65 BSC    |      |      | 0.026 BSC  |       |       |
| E   | 0.55        | 0.60 | 0.65 | 0.022      | 0.024 | 0.026 |
| E1  | 0.15        | 0.20 | 0.25 | 0.006      | 0.008 | 0.010 |
| L   | 0.20        | 0.25 | 0.30 | 0.008      | 0.010 | 0.012 |
| L1  | 0.05 REF    |      |      | 0.0002 REF |       |       |

**Suggested Land Pattern**



| SYM | DIMENSIONS  |        |
|-----|-------------|--------|
|     | MILLIMETERS | INCHES |
| C   | 0.25        | 0.010  |
| X   | 0.65        | 0.024  |
| Y1  | 0.50        | 0.020  |
| Y2  | 0.50        | 0.020  |
| Y3  | 0.25        | 0.010  |
| Z   | 0.20        | 0.008  |

## X-ON Electronics

Largest Supplier of Electrical and Electronic Components

*Click to view similar products for [MOSFETs](#) category:*

*Click to view products by [TECH PUBLIC](#) manufacturer:*

Other Similar products are found below :

[MCH3443-TL-E](#) [MCH6422-TL-E](#) [NTNS3A92PZT5G](#) [IRFD120](#) [2SK2464-TL-E](#) [2SK3818-DL-E](#) [2SJ277-DL-E](#) [2SK2267\(Q\)](#) [MIC4420CM-TR](#) [IRFS350](#) [IPS70R2K0CEAKMA1](#) [AON6932A](#) [2SK2614\(TE16L1,Q\)](#) [DMN1017UCP3-7](#) [EFC2J004NUZTDG](#) [SCM040600](#) [NTE2384](#) [2N7000TA](#) [DMN2080UCB4-7](#) [US6M2GTR](#) [DMN31D5UDJ-7](#) [DMP22D4UFO-7B](#) [DMN1006UCA6-7](#) [DMN16M9UCA6-7](#) [STF5N65M6](#) [IRF40H233XTMA1](#) [STU5N65M6](#) [DMN13M9UCA6-7](#) [STU7N60DM2](#) [DMTH10H4M6SPS-13](#) [DMN2990UFB-7B](#) [2N7002W-G](#) [MCQ7328-TP](#) [IPB45P03P4L11ATMA2](#) [BXP4N65F](#) [BXP2N20L](#) [BXP2N65D](#) [TSM60NB380CP](#) [ROG](#) [SLF10N65ABV2](#) [IRF9395MTRPBF](#) [FCMT080N65S3](#) [NTD5C632NLT4G](#) [NTMFS0D55N03CGT1G](#) [NTMFS1D15N03CGT1G](#) [NTMTS0D4N04CTXG](#) [NTMYS2D1N04CLTWG](#) [NVD360N65S3T4G](#) [NVD5C464NLT4G](#) [NVMTS001N06CLTXG](#) [NVMTS1D1N04CTXG](#)